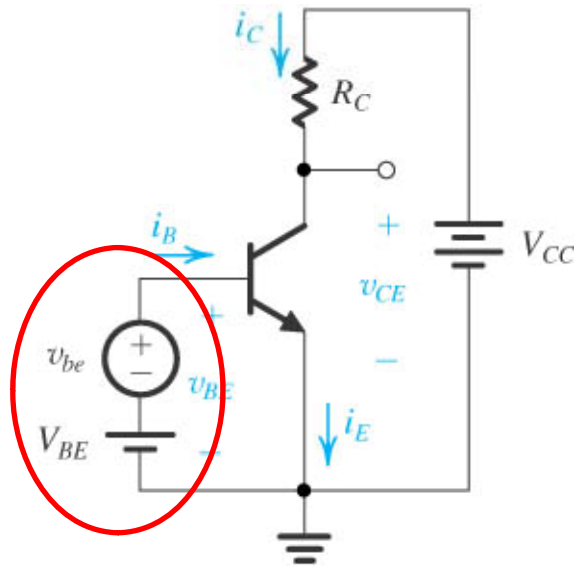


Lect. 12: BJT Small Signal Model (4.4.4 & 4.6.3 in Razavi)



How much change in i_C
for a **small change** in v_{BE} ?

V_{BE}, I_C : Large signal, bias

v_{be}, i_c : small signal, small changes

$$v_{BE} = V_{BE} + v_{be}; \quad V_{BE} \gg v_{be}$$

$$i_C = \alpha i_E = \alpha I_S (e^{v_{BE}/V_T} - 1) \sim I_S e^{v_{BE}/V_T}$$

$$= I_S e^{(V_{BE} + v_{be})/V_T}$$

$$= I_S e^{(V_{BE}/V_T)} e^{(v_{be}/V_T)}$$

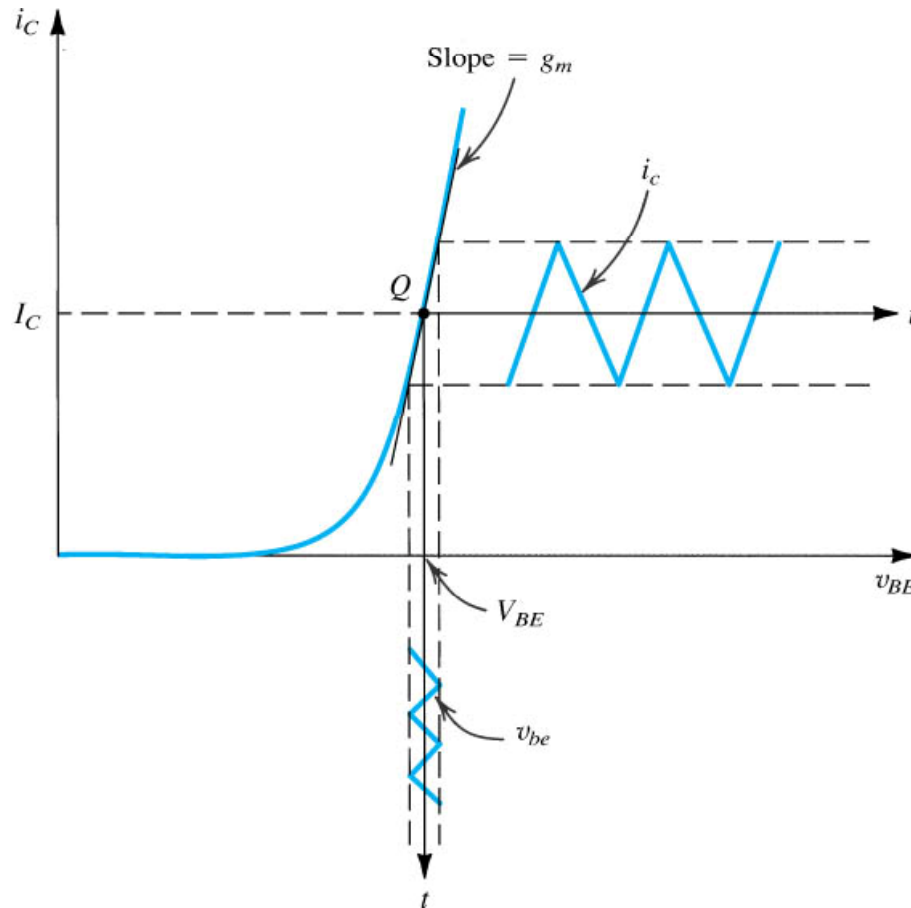
$$\sim I_S e^{(V_{BE}/V_T)} \left(1 + \frac{v_{be}}{V_T}\right)$$

$$= I_C + i_c \quad \text{where } i_c = \frac{I_C}{V_T} \cdot v_{be}$$

$$i_c = g_m \cdot v_{be}$$

$$(g_m = \frac{I_C}{V_T} : \text{transconductance})$$

Lect. 12: BJT Small Signal Model



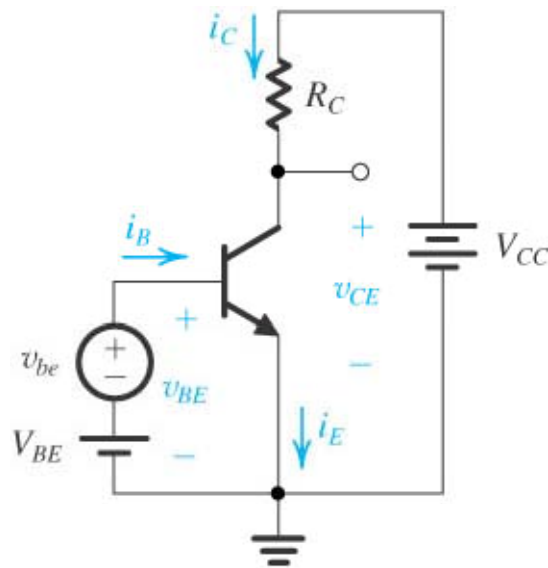
$$i_C = I_S e^{v_{BE}/V_T}$$

$$= I_S e^{(V_{BE} + v_{be})/V_T}$$

$$= I_C + i_c$$

$$i_c = g_m \cdot v_{be} \quad \left(g_m = \frac{I_C}{V_T} \right)$$

Lect. 12: BJT Small Signal Model



(a)

$$i_B = I_B + i_b = ?$$

$$i_E = I_E + i_e = ?$$

$$i_B = \frac{i_C}{\beta} = \frac{I_C}{\beta} + \frac{g_m v_{be}}{\beta}$$

$$i_b = \frac{g_m}{\beta} v_{be} = \frac{i_c}{\beta}$$

$$i_E = \frac{i_C}{\alpha} = \frac{I_C}{\alpha} + \frac{g_m v_{be}}{\alpha}$$

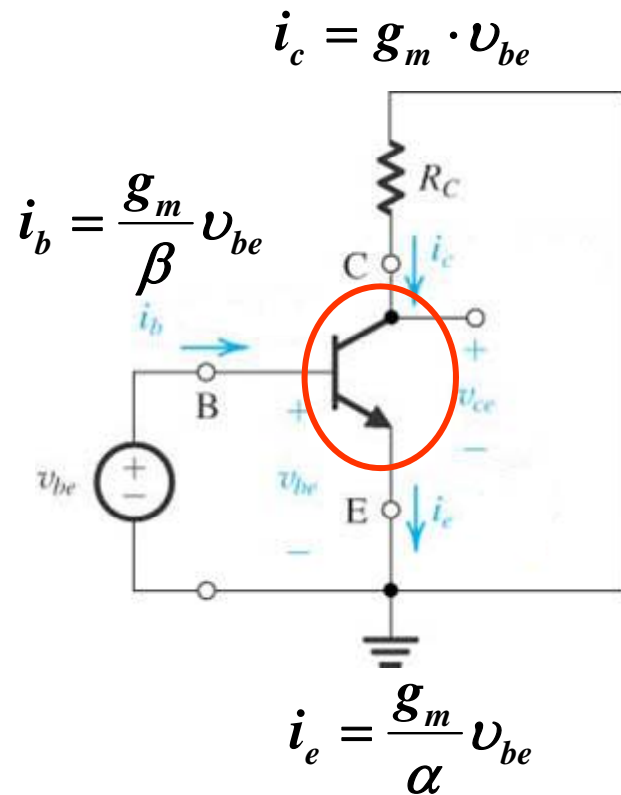
$$i_e = \frac{g_m}{\alpha} v_{be} = \frac{i_c}{\alpha}$$

- All small signal parameters have linear relationship

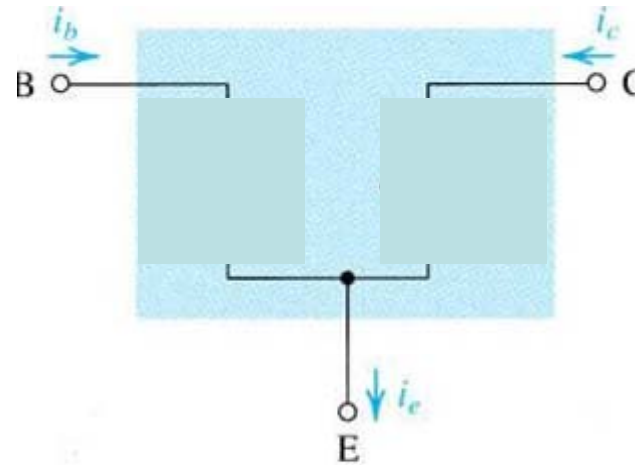
- Their values depend on large signals

Lect. 12: BJT Small Signal Model

Small-signal (linear) circuit Model



Hybrid- π model

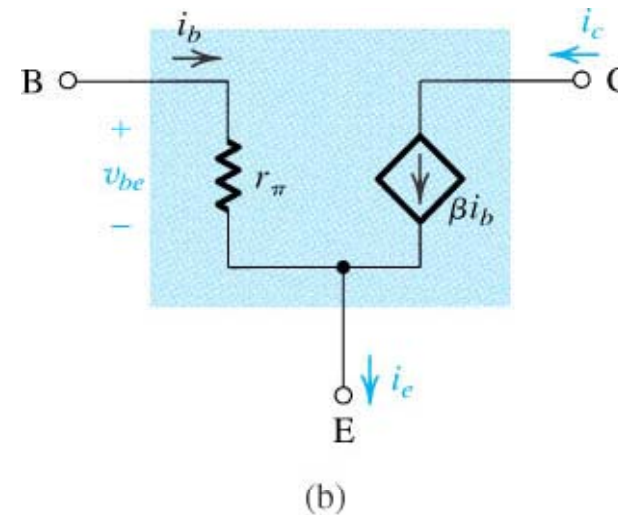
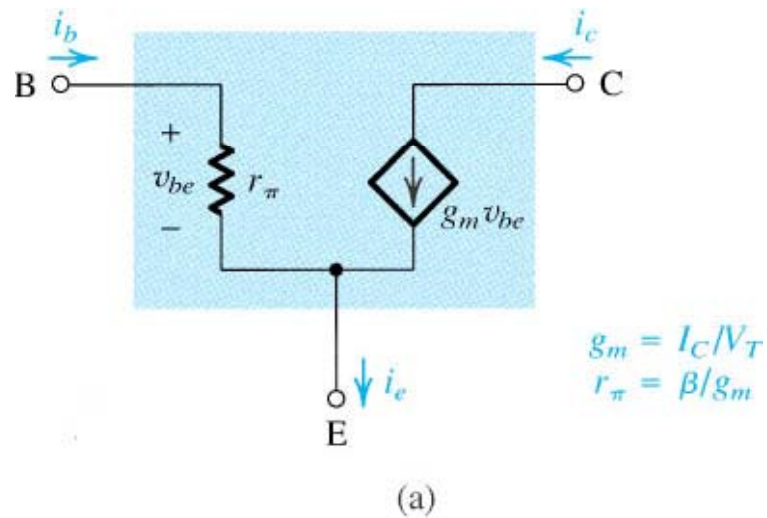


$$r_{\pi} \equiv \frac{v_{be}}{i_b} = \frac{\beta}{g_m}$$

$$= \frac{I_C}{I_B} \cdot \frac{V_T}{I_C} = \frac{V_T}{I_B}$$

Lect. 12: BJT Small Signal Model

Hybrid- π model

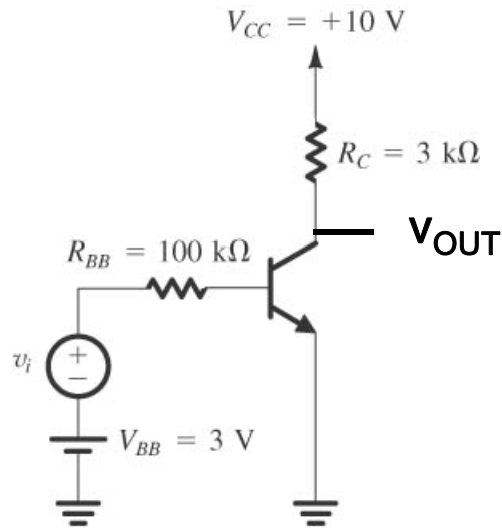


$$\begin{aligned} g_m v_{be} &= g_m (i_b r_\pi) \\ &= (g_m r_\pi) i_b \\ &= \beta i_b \end{aligned}$$

Lect. 12: BJT Small Signal Model

Small signal voltage gain, v_{out}/v_i ?

DC Analysis: Assume $v_i = 0$



(a)

($\beta = 100$)

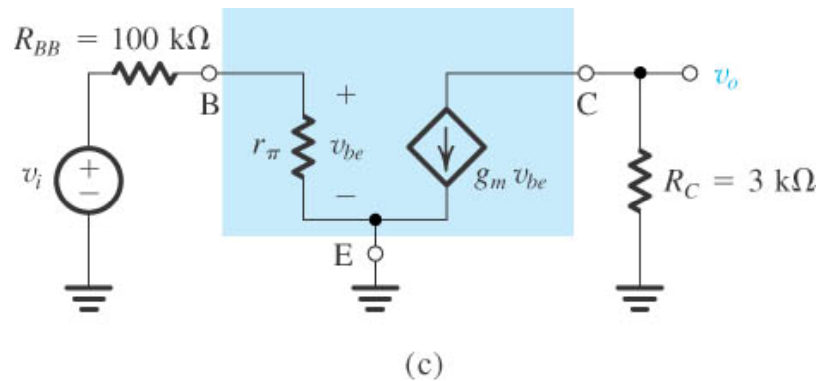
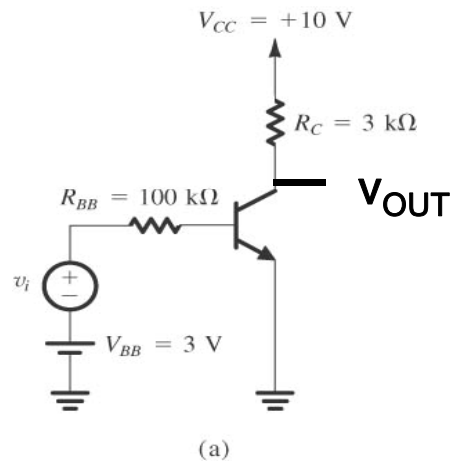
$$I_B = \frac{V_{BB} - V_{BE}}{R_{BB}} = \frac{3 - 0.7}{100} = 0.023 \text{ mA}$$

$$I_C = \beta I_B = 2.3 \text{ mA}$$

$$V_C = V_{CC} - I_C R_C \\ = 10 - 2.3 \times 3 = 3.1 \text{ V}$$

Lect. 12: BJT Small Signal Model

Small-signal analysis



$$g_m = \frac{I_C}{V_T} = \frac{2.3 \text{ mA}}{25 \text{ mV}} = 92 \text{ mA/V}$$

$$r_\pi = \frac{\beta}{g_m} = \frac{100}{92} = 1.09 \text{ k}\Omega$$

$$v_{be} = v_i \frac{r_\pi}{r_\pi + R_{BB}}$$

$$= v_i \frac{1.09}{101.09} = 0.011 v_i$$

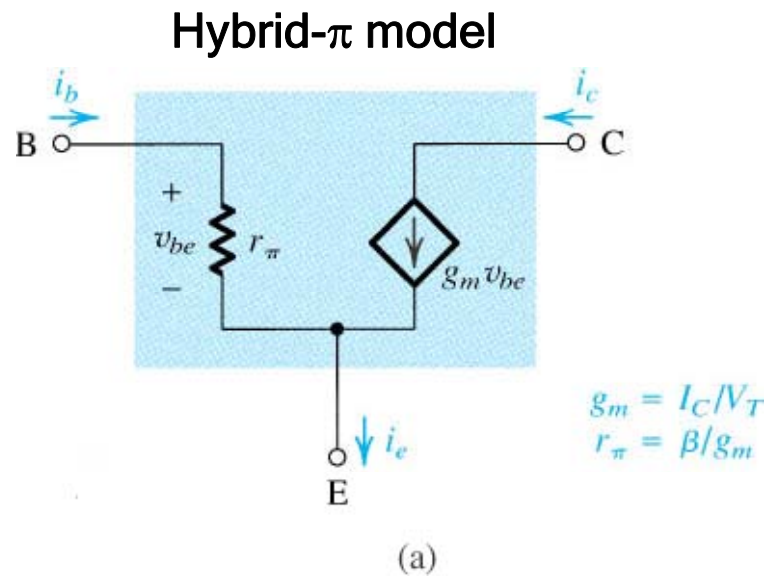
$$v_o = -g_m v_{be} R_C$$

$$= -92 \times 0.011 v_i \times 3 = -3.04 v_i$$

$$A_v = \frac{v_o}{v_i} = -3.04$$

Lect. 12: BJT Small Signal Model

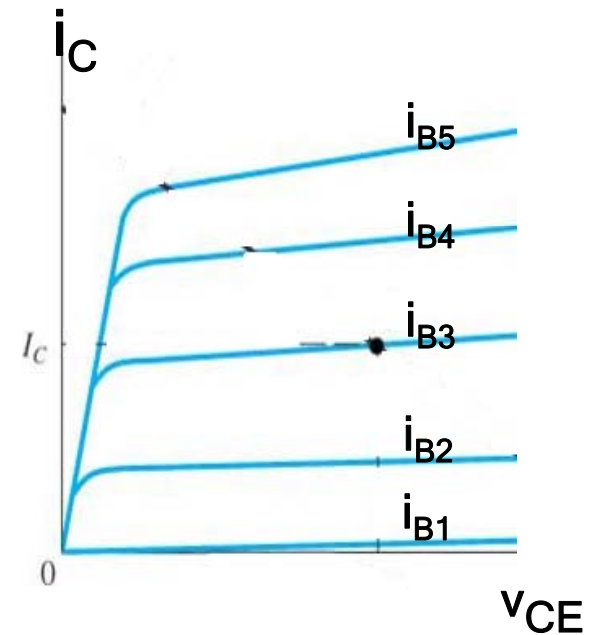
Is the small signal model good enough?



$$i_C = I_S e^{v_{BE} / V_T}$$

i_C should be independent of v_{CE}

But in real BJT devices,

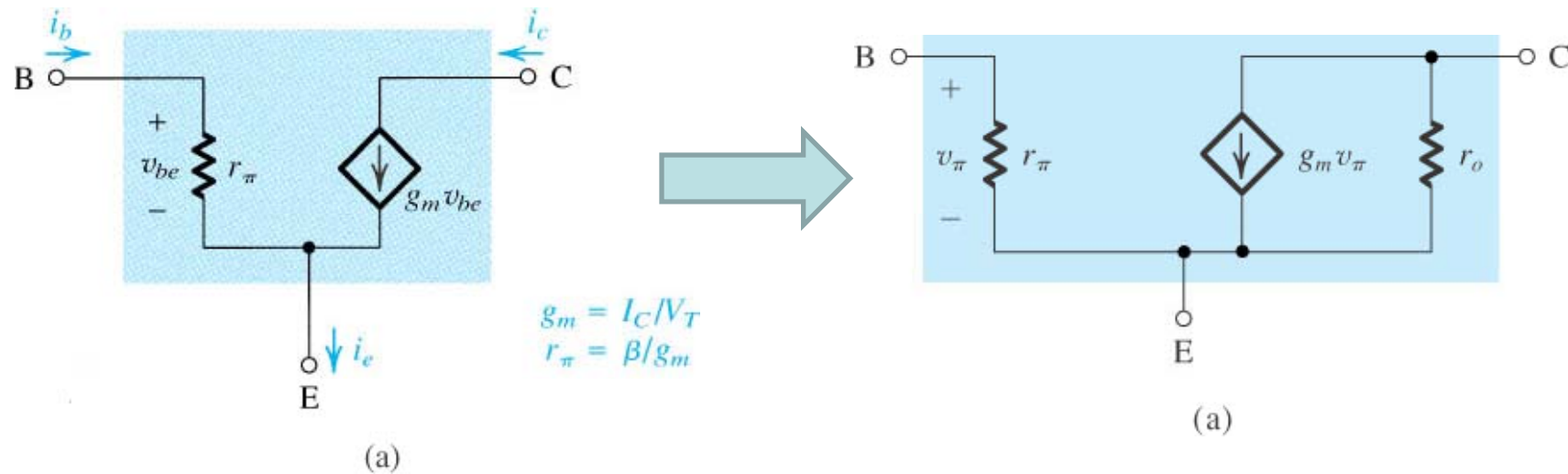


Increase in i_C with v_{CE}
due to Early Effect!

How can we model this?

Lect. 12: BJT Small Signal Model

Hybrid- π model

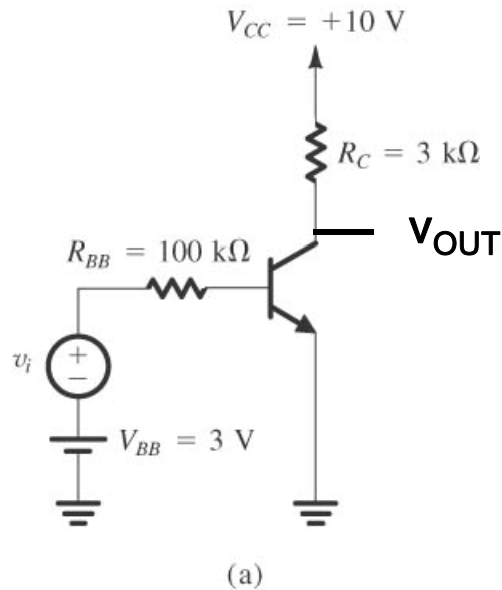


r_o depends on BJTs

Typically, in the order of 100k Ω

Lect. 12: BJT Small Signal Model

DC Analysis ($\beta = 100$, $r_o = 100\text{k}\Omega$)



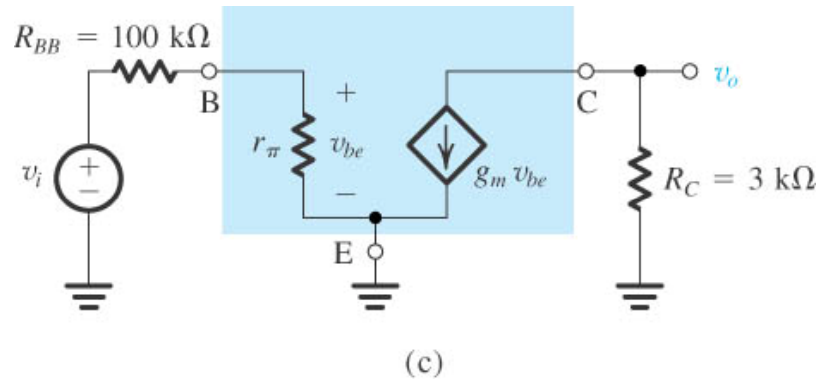
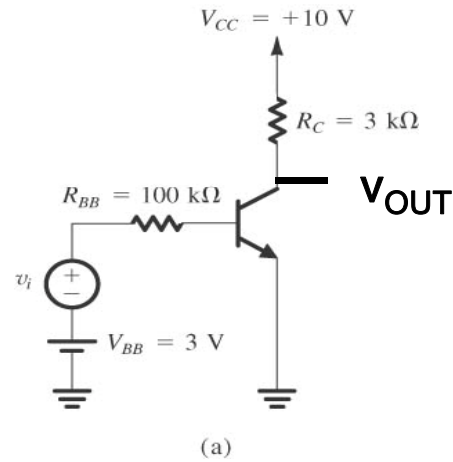
$$I_B = \frac{V_{BB} - V_{BE}}{R_{BB}}$$
$$\sim \frac{3 - 0.7}{100} = 0.023 \text{ mA}$$

$$I_C = \beta I_B = 100 \times 0.023 = 2.3 \text{ mA}$$

$$V_C = V_{CC} - i_C R_C$$
$$= +10 - 2.3 \times 3 = +3.1 \text{ V}$$

Lect. 12: BJT Small Signal Model

Small-signal analysis



$$g_m = \frac{I_C}{V_T} = \frac{2.3 \text{ mA}}{25 \text{ mV}} = 92 \text{ mA/V}$$

$$r_\pi = \frac{\beta}{g_m} = \frac{100}{92} = 1.09 \text{ } \Omega$$

$$v_{be} = v_i \frac{r_\pi}{r_\pi + R_{BB}}$$

$$= v_i \frac{1.09}{101.09} = 0.011 v_i$$

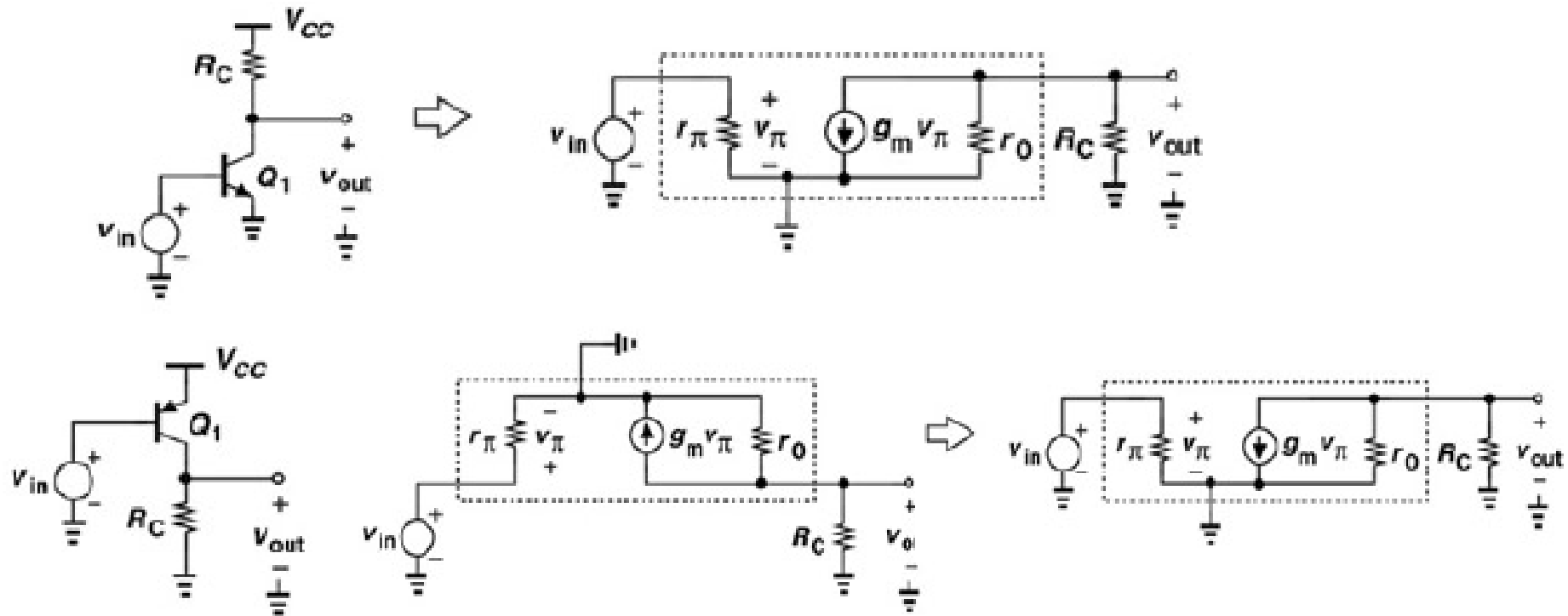
$$v_o = -g_m v_{be} (R_C \parallel r_o)$$

$$= -92 \times 0.011 v_i \times (3 \parallel 100) = -2.95 v_i$$

$$A_v = \frac{v_o}{v_i} = -2.95 \text{ V/V}$$

Lect. 12: BJT Small Signal Model

Small signal model for PNP?



Small signal models for PNP and NPN are identical!